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Kind regards,

Team Nexperia

INTEGRATED CIRCUITS

DATA SHEET

74ALVCH16821

20-bit bus-interface D-type flip-flop; positive-edge trigger (3-State)

Product specification

1998 May 29

IC24 Data Handbook





20-bit bus-interface D-type flip-flop; positive-edge trigger (3-State)

74ALVCH16821

FEATURES

- Wide supply voltage range of 1.2V to 3.6V
- Complies with JEDEC standard no. 8-1A
- Current drive ± 24 mA at 3.0 V
- CMOS low power consumption
- Direct interface with TTL levels
- MULTIBYTETM flow-through standard pin-out architecture
- Low inductance multiple V_{CC} and ground pins for minimum noise and ground bounce
- All data inputs have bus hold
- Output drive capability 50Ω transmission lines @ 85°C

DESCRIPTION

The 74ALVCH16821 has two 10-bit, edge triggered registers, with each register coupled to a 3-State output buffer. The two sections of each register are controlled independently by the clock (nCP) and Output Enable (nOE) control gates.

Each register is fully edge triggered. The state of each D input, one set-up time before the Low-to-High clock transition, is transferred to the corresponding flip-flop's Q output.

When $n\overline{OE}$ is LOW, the data in the register appears at the outputs. When nOE is HIGH, the outputs are in high impedance OFF state. Operation of the nOE input does not affect the state of the flip-flops.

The 74ALVCH16821 has active bus hold circuitry which is provided to hold unused or floating data inputs at a valid logic level. This feature eliminates the need for external pull-up or pull-down resistors.

QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ns}$

SYMBOL	PARAMETER	CONDITI	ONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay nCP to nQ _n	V _{CC} = 2.5V, C _L = 30pF V _{CC} = 3.3V, C _L = 50pF	2.6 2.5	ns	
Cl	Input capacitance		5.0	pF	
	Dower dissipation appositance per buffer	$V_1 = GND \text{ to } V_{CC}^{-1}$	Outputs enabled	33	pF
C _{PD}	Power dissipation capacitance per buffer	$\Lambda_1 = \text{GMD to } \Lambda^{CC}$.	Outputs disabled	17	рг
F _{max}	Maximum clock frequency	$V_{CC} = 2.5V, C_L = 30pF$ $V_{CC} = 3.3V, C_L = 50pF$		250 350	MHz

NOTE:

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 $f_0 = OPD \times CC \times f_0$ and $f_0 = OPD \times CC \times f_0$ which is input frequency in MHz; $C_L = OPD \times f_0$ output frequency in MHz; $V_{CC} = OPD \times f_0$ output frequ

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER	
56-Pin Plastic SSOP Type III	-40°C to +85°C	74ALVCH16821 DL	ACH16821 DL	SOT371-1	
56-Pin Plastic TSSOP Type II	-40°C to +85°C	74ALVCH16821 DGG	ACH16821 DGG	SOT364-1	

 C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

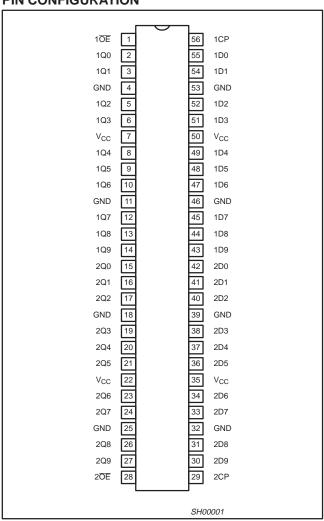
20-bit bus-interface D-type flip-flop; positive-edge trigger (3-State)

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PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
55, 54, 52, 51, 49, 48, 47, 45, 44, 43	1D0 - 1D9	Data inputs
42, 41, 40, 38, 37, 36, 34, 33, 31, 30	2D0 - 2D9	Data inputs
2, 3, 5, 6, 8, 9, 10, 12, 13, 14	1Q0 - 1Q9	Data outputs
15, 16, 17, 19, 20, 21, 23, 24, 26, 27	2Q0 - 2Q9	Bata datpats
1, 28	10E, 20E	Output enable inputs (active-Low)
56, 29	1CP, 2CP	Clock pulse inputs (active rising edge)
4, 11, 18, 25, 32, 39, 46, 53	GND	Ground (0V)
7, 22, 35, 50	V _{CC}	Positive supply voltage

PIN CONFIGURATION



FUNCTION TABLE

	INPUTS	OUTPUT	
nŌĒ	СР	Dx	Q
L	1	L	L
L	1	Н	Н
L	‡	Х	Q0
Н	X	Х	Z

H = HIGH voltage level

L = LOW voltage level

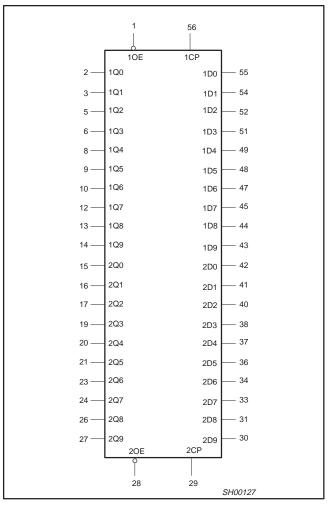
X = Don't care

Z = High impedance OFF state

↑ = LOW to HIGH clock transition

‡ = Not a LOW-to-HIGH clock transition

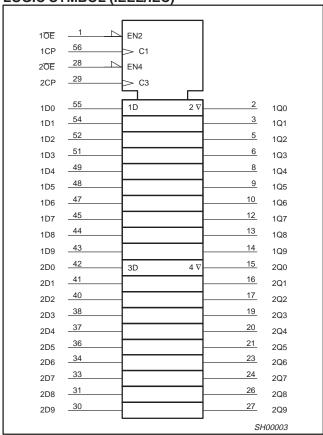
LOGIC SYMBOL



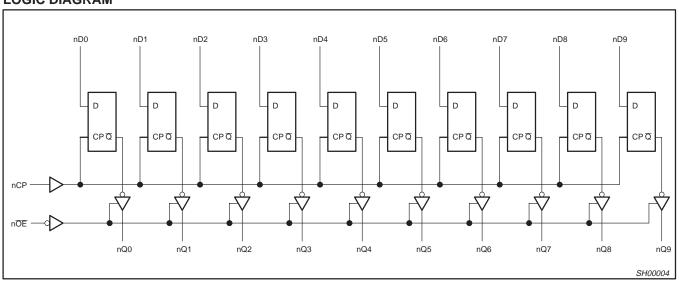
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LOGIC DIAGRAM



20-bit bus-interface D-type flip-flop; positive-edge trigger (3-State)

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIM	IITS	UNIT
STWIBUL	PARAMETER	CONDITIONS	MIN	MIN MAX	
V	DC supply voltage 2.5V range (for max. speed performance @ 30 pF output load)		2.3	2.7	V
V _{CC}	DC supply voltage 3.3V range (for max. speed performance @ 50 pF output load)		3.0	3.6	V
VI	DC Input voltage range		0	V _{CC}	V
Vo	DC output voltage range		0	V _{CC}	V
T _{amb}	Operating free-air temperature range		-40	+85	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 2.3 \text{ to } 3.0 \text{V}$ $V_{CC} = 3.0 \text{ to } 3.6 \text{V}$	0	20 10	ns/V

ABSOLUTE MAXIMUM RATINGS

In accordance with the Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
\/	DC input voltage	For control pins ¹	-0.5 to +4.6	V
VI	DC Input voltage	For data inputs ¹	–0.5 to V _{CC} +0.5	1 '
I _{OK}	DC output diode current	$V_{O} > V_{CC}$ or $V_{O} < 0$	±50	mA
Vo	DC output voltage	Note 1	–0.5 to V _{CC} +0.5	V
I _O	DC output source or sink current	$V_O = 0$ to V_{CC}	±50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		±100	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package –plastic medium-shrink (SSOP) –plastic thin-medium-shrink (TSSOP)	For temperature range: -40 to +125 °C above +55°C derate linearly with 11.3 mW/K above +55°C derate linearly with 8 mW/K	850 600	mW

NOTE

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^{1.} The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltage are referenced to GND (ground = 0 V).

				LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS	Temp :	= -40°C to +8	5°C	UNIT
			MIN	TYP ¹	MAX	1
.,,	LHOLLI Liver to refer to	V _{CC} = 2.3 to 2.7V	1.7	1.2		
V_{IH}	HIGH level Input voltage	V _{CC} = 2.7 to 3.6V	2.0	1.5		٧
	LOW lovel leavet value	V _{CC} = 2.3 to 2.7V		1.2	0.7	V
V_{IL}	LOW level Input voltage	V _{CC} = 2.7 to 3.6V		1.5	0.8	1 '
		V_{CC} = 2.3 to 3.6V; V_I = V_{IH} or V_{IL} ; I_O = $-100\mu A$	V _{CC} -0.2	V _{CC}		
		$V_{CC} = 2.3V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -6mA$	V _{CC} -0.3	V _{CC} -0.08		1
W	LHCLL lovel output voltage	$V_{CC} = 2.3V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -12mA$	V _{CC} -0.6	V _{CC} -0.26		
V _{OH}	HIGH level output voltage	$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -12mA$	V _{CC} -0.5	V _{CC} -0.14		1 °
		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -12mA$	V _{CC} -0.6	V _{CC} -0.09		1
		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -24$ mA	V _{CC} -1.0	V _{CC} -0.28		1
		V_{CC} = 2.3 to 3.6V; V_I = V_{IH} or V_{IL} ; I_O = 100 μ A		GND	0.20	٧
		$V_{CC} = 2.3V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 6mA$		0.07	0.40	V
V_{OL}	LOW level output voltage	$V_{CC} = 2.3V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 12mA$		0.15	0.70	
		$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 12mA$		0.14	0.40	V
		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 24mA$		0.27	0.55]
IĮ	Input leakage current	$V_{CC} = 2.3 \text{ to } 3.6V;$ $V_I = V_{CC} \text{ or GND}$		0.1	5	μА
I _{OZ}	3-State output OFF-state current	V_{CC} = 2.7 to 3.6V; V_I = V_{IH} or V_{IL} ; V_O = V_{CC} or GND		0.1	10	μА
I _{CC}	Quiescent supply current	$V_{CC} = 2.3$ to 3.6V; $V_I = V_{CC}$ or GND; $I_O = 0$		0.2	40	μΑ
Δl _{CC}	Additional quiescent supply current	$V_{CC} = 2.3V$ to 3.6V; $V_I = V_{CC} - 0.6V$; $I_O = 0$		150	750	μΑ
	Due held LOW sustaining surrent	$V_{CC} = 2.3V; V_I = 0.7V^2$	45	-		
I _{BHL}	Bus hold LOW sustaining current	$V_{CC} = 3.0V; V_I = 0.8V^2$	75	150		μΑ
	Due hold IIICH eustainin a summer	$V_{CC} = 2.3V; V_I = 1.7V^2$	-45			
I _{BHH}	Bus hold HIGH sustaining current	$V_{CC} = 3.0V; V_1 = 2.0V^2$	-75	-175		μΑ
I _{BHLO}	Bus hold LOW overdrive current	$V_{CC} = 3.6V^2$	500			μΑ
I _{BHHO}	Bus hold HIGH overdrive current	$V_{CC} = 3.6V^2$	-500			μА

All typical values are at T_{amb} = 25°C.
 Valid for data inputs of bus hold parts.

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AC CHARACTERISTICS FOR $V_{CC} = 2.3V$ TO 2.7V RANGE

 $GND = 0V; \ t_r = t_f \leq 2.0 ns; \ C_L = 30 pF$

				LIMITS		
SYMBOL	PARAMETER	WAVEFORM	٧c	UNIT		
			MIN	TYP ¹	MAX	1 1
t _{PLH} /t _{PHL}	Propagation delay nCP to nQ _n	1, 4	1.0	2.6	5.8	ns
t _{PZH} /t _{PZL}	3-State output enable time $n\overline{OE}_n$ to nQ_n	2, 4	1.0	2.8	6.6	ns
t _{PHZ} /t _{PLZ}	3-State output disable time $n\overline{\text{OE}}_n$ to nQ_n	2, 4	1.0	2.2	5.7	ns
t _W	nCP pulse width HIGH or LOW	3, 4	3.0	1.8		ns
t _{SU}	Set up time nD _n to nCP	3, 4	1.4	0.3		ns
t _h	Hold time nD _n to nCP	3, 4	0.4	0.0		ns
F _{max}	Maximum clock pulse frequency	1, 4	150	250		MHz

AC CHARACTERISTICS FOR V_{CC} = 3.0V TO 3.6V RANGE AND V_{CC} = 2.7V GND = 0V; $t_r = t_f \le 2.5$ ns; $C_L = 50$ pF

					LIM	ITS			
SYMBOL	PARAMETER	WAVEFORM	٧ _C	$_{\text{C}}$ = 3.3 \pm 0	.3V	,	UNIT		
			MIN	TYP ¹	MAX	MIN	TYP ¹	MAX	
t _{PHL} /t _{PLH}	Propagation delay nCP to nQ _n	1, 4	1.0	2.5	4.5	1.0	2.8	5.3	ns
t _{PZH} /t _{PZL}	3-State output enable time nOE _n to nQ _n	2, 4	1.0	2.3	5.1	1.0	3.2	6.2	ns
t _{PHZ} /t _{PLZ}	3-State output disable time nOE _n to nQ _n	2, 4	1.0	2.8	4.6	1.0	3.1	5.0	ns
t _W	nCP pulse width HIGH or LOW	3, 4	3.3	0.2		3.3	1.7		ns
t _{SU}	Set up time nD _n to nCP	3, 4	1.0	0.2		1.2	0.3		ns
t _h	Hold time nD _n to nCP	3, 4	0.8	0.4		0.6	-0.3		ns
F _{max}	Maximum clock pulse frequency	1, 4	150	350		150	300		MHz

NOTES:

^{1.} All typical values are at V_{CC} = 2.5V and T_{amb} = 25°C.

^{1.} All typical values are at $T_{amb} = 25^{\circ}C$.

20-bit bus-interface D-type flip-flop; positive-edge trigger (3-State)

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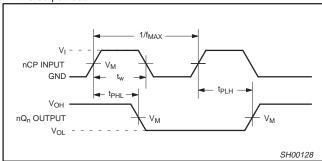
AC WAVEFORMS

V_{CC} = 2.3 TO 2.7 V RANGE

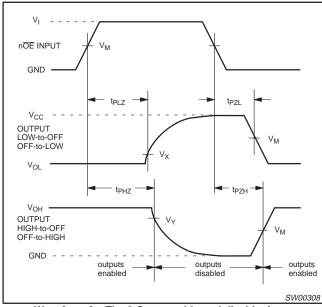
- $V_{M} = 0.5 V$
- 2. $V_X = V_{OL} + 0.15V$
- 3. $V_Y = V_{OH} 0.15V$
- 4. V_I = V_{CC}
 5. V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

V_{CC} = 3.0 TO 3.6 V RANGE AND V_{CC} = 2.7 V 1. V_{M} = 1.5 V

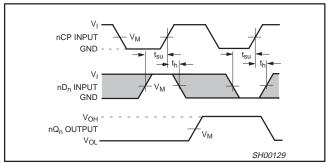
- 2. $V_X^{(1)} = V_{OL} + 0.3V$
- 3. $V_Y = V_{OH} 0.3V$ 4. $V_I = 2.7 V$
- 5. VOL and VOH are the typical output voltage drop that occur with the output load.



The input (nCP) to output propagation delays.

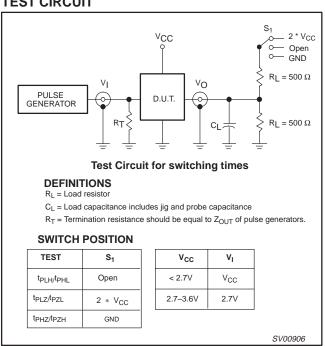


Waveform 2. The 3-State enable and disable times.



Waveform 3. Set up and hold times.

TEST CIRCUIT



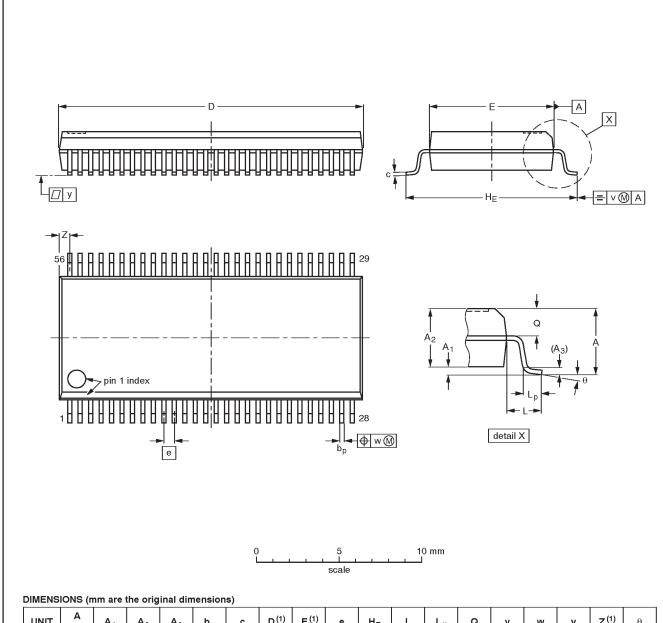
Waveform 4. Load circuitry for switching times

20-bit bus-interface D-type flip-flop; positive-edge trigger (3-State)

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SSOP56: plastic shrink small outline package; 56 leads; body width 7.5 mm

SOT371-1



UNIT	A max.	Α ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	18.55 18.30	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

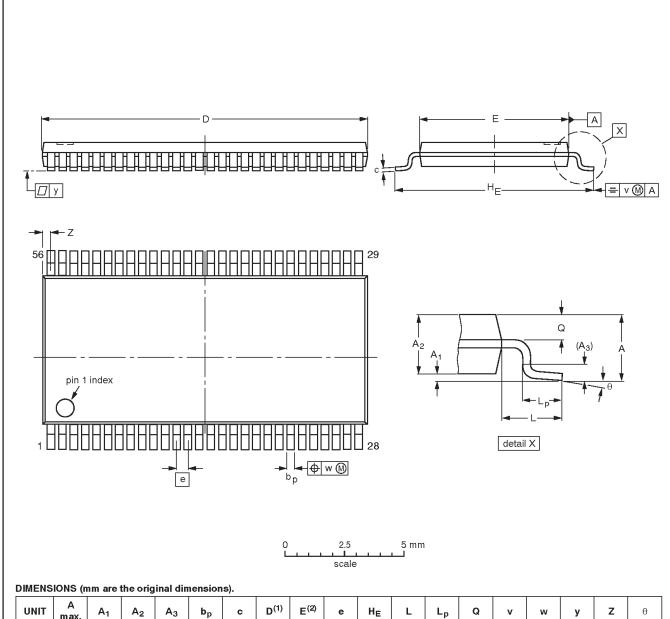
OUTLINE		REFER	RENCES	ISSUE DATE		
VERSION	VERSION IEC		EIAJ	PROJECTION	ISSUE DATE	
SOT371-1		MO-118AB				93-11-02 95-02-04

20-bit bus-interface D-type flip-flop; positive-edge trigger (3-State)

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TSSOP56: plastic thin shrink small outline package; 56 leads; body width 6.1mm

SOT364-1



UNIT	A max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	٧	w	у	z	θ
mm	1.2	0.15 0.05	1.05 0.85	0.25	0.28 0.17	0.2 0.1	14.1 13.9	6.2 6.0	0.5	8.3 7.9	1.0	0.8 0.4	0.50 0.35	0.25	0.08	0.1	0.5 0.1	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1330E DATE
SOT364-1		MO-153EE				-93-02-03 95-02-10

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20-bit bus-interface D-type flip-flop; positive-edge trigger (3-State)

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NOTES

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Data sheet status

Data sheet status	Product status	Definition [1]	
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.	
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.	
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.	

^[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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